

BULB7216 BUL7216

High voltage fast-switching NPN power transistor

Features

- Low spread of dynamic parameters
- High voltage capability
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

Applications

 Electronic ballast for fluorescent lighting (277 V push-pull and 347 V half bridge topoligies)

Description

The devices are manufactured using diffused collector technology to enhance switching speeds and tight h_{FE} while maintaining the wide RBSOA.

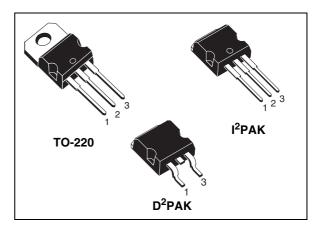
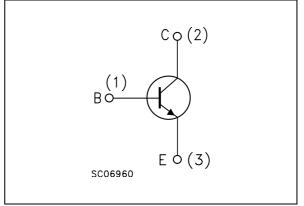


Figure 1. Internal schematic diagram



Order code	Marking	Package	Packaging
BUL7216	BUL7216	TO-220	Tube
BULB7216-1	BULB7216	I ² PAK	Tube
BULB7216T4	BULB7216	D ² PAK	Tape and reel

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Electrical ratings

Symbol	Parameter	Value	Unit
V _{CES}	Collector-emitter voltage (V _{BE} = 0)	1600	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	700	V
V _{EBO}	Emitter-base voltage (I _C = 0)	12	V
Ι _C	Collector current	3	А
I _{CM}	Collector peak current (t _P < 5ms)	6	Α
Ι _Β	Base current	1	Α
I _{BM}	Base peak current (t _P < 5ms)	2	A
P _{tot}	Total dissipation at $T_c = 25^{\circ}C$	80	W
T _{stg} Storage temperature		-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal resistance junction - case	1.56	°C/W



2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$

Table 4.	Electrical characteristi	cs

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} =1600 V V _{CE} =1600 V T _C = 125 °C			0.1 0.5	mA mA
I _{CEO}	Collector cut-off current $(I_B = 0)$	V _{CE} =680 V			0.1	mA
I _{CBO}	Collector cut-off current (I _E = 0)	V _{CB} =1600 V V _{CB} =1600 V T _C = 125 °C			0.1 0.5	mA mA
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} =12 V			1	mA
V _{(BR)CEO} ⁽¹⁾	Collector-emitter breakdown voltage $(I_B = 0)$	I _C = 1 mA	700			v
V _{(BR)EBO} ⁽¹⁾	Emitter-base breakdown voltage (I _C = 0)	I _E = 1 mA	12			V
V _{(BR)CES} ⁽¹⁾	Collector-emitter breakdown voltage (V _{BE} = 0)	I _C = 0.1 mA	1600			v
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage				1 1.5 3	
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage				1 1.1 1.2	V V V
h _{FE} ⁽¹⁾	DC current gain		16 4		18 35 11	
t _d t _r t _s t _f	Resistive load Delay time Rise time Storage time Fall time	$I_{C} = 0.5 \text{ A} \qquad V_{CC} = 125 \text{ V}$ $I_{B1} = 50 \text{ mA} \qquad I_{B2} = -0.5 \text{ A}$ $P.W. = 300 \mu \text{s} \qquad D.C. = 2\%$ $L = 2 \text{ mH} \qquad C = 1.8 \text{ nF}$			0.3 1.1 0.9 0.35	μs μs μs μs
E _{ar}	Repetitive avalanche energy	$V_{BE(off)} = -5 V$	8			mJ

1. Pulsed duration = 300 $\mu s,$ duty cycle $~\leq 1.5\%$



Electrical characteristics (curves) 2.1

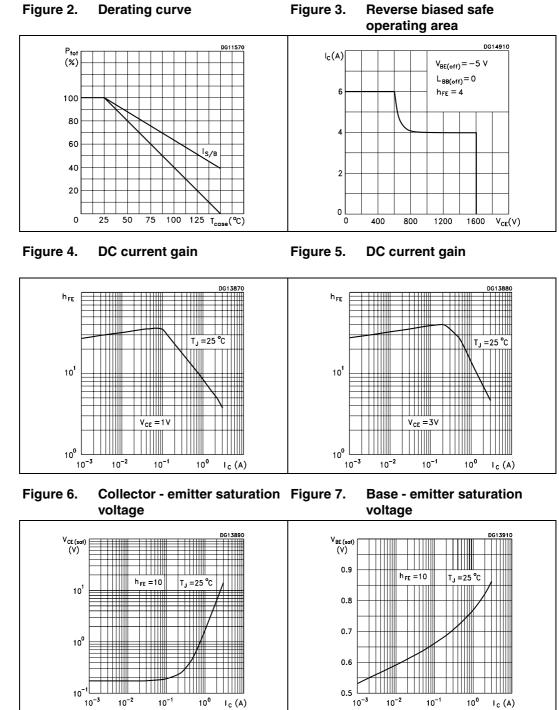


Figure 2. **Derating curve**

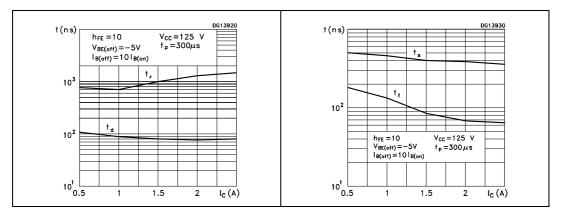
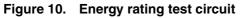


Figure 8. Resistive load switching time Figure 9. Resistive load switching time



3 Test circuit



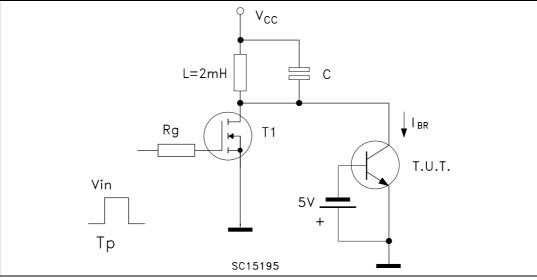
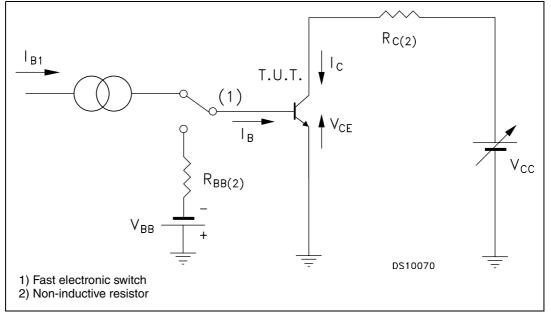


Figure 11. Resistive load switching test circuit





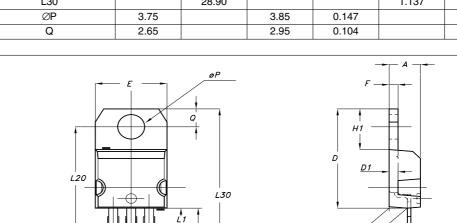
4 Package mechanical data

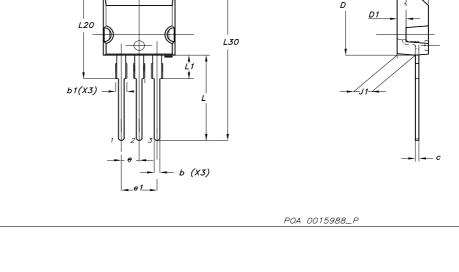
In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com



Dim		mm			inch		
Dim	Min	Тур	Мах	Min	Тур	Max	
Α	4.40		4.60	0.173		0.181	
b	0.61		0.88	0.024		0.034	
b1	1.14		1.70	0.044		0.066	
С	0.49		0.70	0.019		0.027	
D	15.25		15.75	0.6		0.62	
D1		1.27			0.050		
E	10		10.40	0.393		0.409	
е	2.40		2.70	0.094		0.106	
e1	4.95		5.15	0.194		0.202	
F	1.23		1.32	0.048		0.051	
H1	6.20		6.60	0.244		0.256	
J1	2.40		2.72	0.094		0.107	
L	13		14	0.511		0.551	
L1	3.50		3.93	0.137		0.154	
L20		16.40			0.645		
L30		28.90			1.137		
ØP	3.75		3.85	0.147		0.151	
Q	2.65		2.95	0.104		0.116	

TO-220 mechanical data



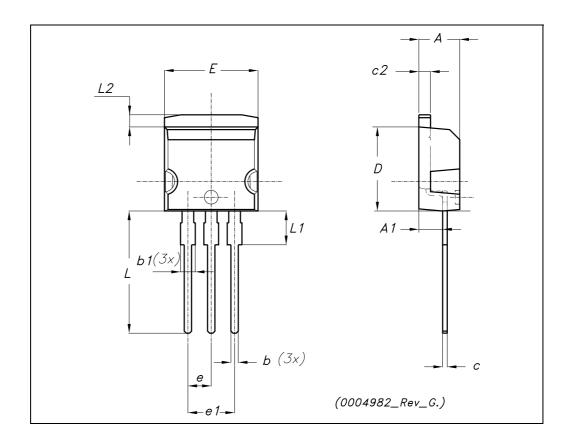




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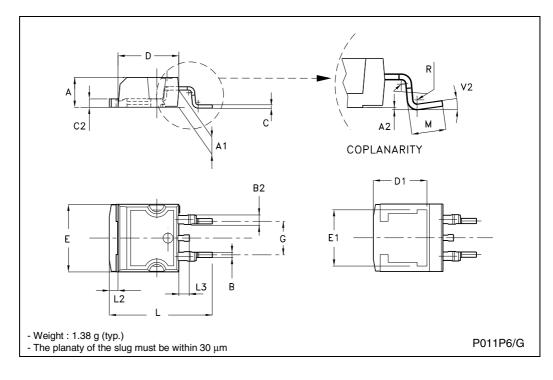
DIM.		mm.			inch	
DIW.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.
А	4.40		4.60	0.173		0.181
A1	2.40		2.72	0.094		0.107
b	0.61		0.88	0.024		0.034
b1	1.14		1.70	0.044		0.066
С	0.49		0.70	0.019		0.027
c2	1.23		1.32	0.048		0.052
D	8.95		9.35	0.352		0.368
е	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
Е	10		10.40	0.393		0.410
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L2	1.27		1.40	0.050		0.055

TO-262 (I²PAK) MECHANICAL DATA



DIM.		mm			inch		
Diwi.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А	4.40		4.60	0.173		0.181	
A1	2.49		2.69	0.098		0.106	
A2	0.03		0.23	0.001		0.009	
В	0.70		0.93	0.027		0.036	
B2	1.14		1.70	0.044		0.067	
С	0.45		0.60	0.017		0.023	
C2	1.23		1.36	0.048		0.053	
D	8.95		9.35	0.352		0.368	
D1		8.00			0.315		
Е	10.00		10.40	0.393		0.409	
E1		8.50			0.334		
G	4.88		5.28	0.192		0.208	
L	15.00		15.85	0.590		0.624	
L2	1.27		1.4	0.050		0.055	
L3	1.40		1.75	0.055		0.068	
М	2.40		3.2	0.094		0.126	
R		0.40			0.016		

TO-263 (D²PAK) MECHANICAL DATA





5 Revision history

Table 5.Document revision history

Date	Revision	Changes
17-Jan-2006	1	First release.
28-Nov-2007	2	Added packages D ² PAK and I ² PAK



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